74HC2G14; 74HCT2G14

Dual inverting Schmitt trigger

Rev. 3 — 28 January 2022

Product data sheet

1. General description

The 74HC2G14; 74HCT2G14 is a dual inverter with Schmitt-trigger inputs. Inputs include clamp diodes. This enables the use of current limiting resistors to interface inputs to voltages in excess of V_{CC} . Schmitt trigger inputs transform slowly changing input signals into sharply defined jitter-free output signals.

2. Features and benefits

- Wide supply voltage range from 2.0 V to 6.0 V
- Input levels:
 - For 74HC2G14: CMOS level
 - For 74HCT2G14: TTL level
- · High noise immunity
- CMOS low power dissipation
- · Balanced propagation delays
- Unlimited input rise and fall times
- Latch-up performance exceeds 100 mA per JESD 78 Class II Level B
- · Complies with JEDEC standards
 - JESD8C (2.7 V to 3.6 V)
 - JESD7A (2.0 V to 6.0 V)
- ESD protection:
 - HBM JESD22-A114E exceeds 2000 V
 - MM JESD22-A115-A exceeds 200 V
- Specified from -40 °C to +85 °C and -40 °C to +125 °C

3. Applications

- · Wave and pulse shaper for highly noisy environments
- · Astable multivibrators
- · Monostable multivibrators

4. Ordering information

Table 1. Ordering information

| Type number | Package | | | | | | | | | |
|-------------|-------------------|--------|---|----------|--|--|--|--|--|--|
| | Temperature range | Name | Description | Version | | | | | | |
| 74HC2G14GW | -40 °C to +125 °C | TSSOP6 | plastic thin shrink small outline package; 6 leads; | SOT363-2 | | | | | | |
| 74HCT2G14GW | | | body width 1.25 mm | | | | | | | |
| 74HC2G14GV | -40 °C to +125 °C | SC-74; | plastic surface-mounted package; 6 leads | SOT457 | | | | | | |
| 74HCT2G14GV | | TSOP6 | | | | | | | | |



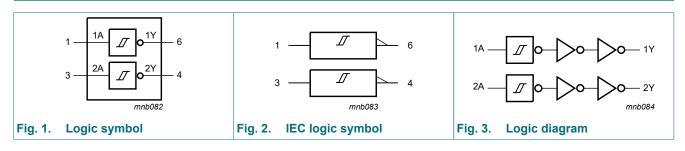
5. Marking

Table 2. Marking

| Type number | Marking code[1] |
|-------------|-----------------|
| 74HC2G14GW | нк |
| 74HCT2G14GW | тк |
| 74HC2G14GV | H14 |
| 74HCT2G14GV | T14 |

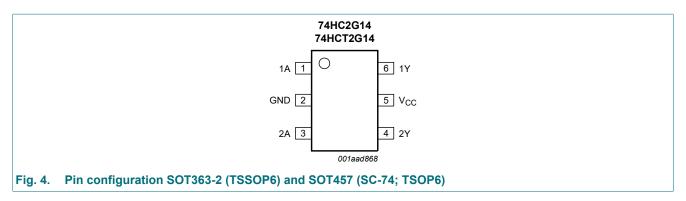
^[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

6. Functional diagram



7. Pinning information

7.1. Pinning



7.2. Pin description

Table 3. Pin description

| Symbol | Pin | Description |
|-----------------|-----|----------------|
| 1A | 1 | data input |
| GND | 2 | ground (0 V) |
| 2A | 3 | data input |
| 2Y | 4 | data output |
| V _{CC} | 5 | supply voltage |
| 1Y | 6 | data output |

8. Functional description

Table 4. Function table

 $H = HIGH \ voltage \ level; \ L = LOW \ voltage \ level.$

| Input | Output |
|-------|--------|
| nA | nY |
| L | Н |
| Н | L |

9. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

| Symbol | Parameter | Conditions | Min | Max | Unit |
|------------------|-------------------------|---|------|------|------|
| V _{CC} | supply voltage | | -0.5 | +7.0 | V |
| I _{IK} | input clamping current | $V_I < -0.5 \text{ V or } V_I > V_{CC} + 0.5 \text{ V}$ [1] | - | ±20 | mA |
| I _{OK} | output clamping current | $V_O < -0.5 \text{ V or } V_O > V_{CC} + 0.5 \text{ V}$ [1] | - | ±20 | mA |
| lo | output current | $V_O = -0.5 \text{ V to } V_{CC} + 0.5 \text{ V}$ [1] | - | ±25 | mA |
| I _{CC} | supply current | [1] | - | +50 | mA |
| I _{GND} | ground current | [1] | - | -50 | mA |
| T _{stg} | storage temperature | | -65 | +150 | °C |
| P _{tot} | total power dissipation | [2] | - | 250 | mW |

^[1] The minimum input and output voltage ratings may be exceeded if the input and output current ratings are observed.

10. Recommended operating conditions

Table 6. Recommended operating conditions

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit | | | | |
|------------------|---------------------|------------|-----|-----|-----------------|------|--|--|--|--|
| 74HC2G | 74HC2G14 | | | | | | | | | |
| V _{CC} | supply voltage | | 2.0 | 5.0 | 6.0 | V | | | | |
| VI | input voltage | | 0 | - | V _{CC} | V | | | | |
| Vo | output voltage | | 0 | - | V _{CC} | V | | | | |
| T _{amb} | ambient temperature | | -40 | +25 | +125 | °C | | | | |
| 74HCT20 | G14 | | | | | | | | | |
| V _{CC} | supply voltage | | 4.5 | 5.0 | 5.5 | V | | | | |
| VI | input voltage | | 0 | - | V _{CC} | V | | | | |
| Vo | output voltage | | 0 | - | V _{CC} | V | | | | |
| T _{amb} | ambient temperature | | -40 | +25 | +125 | °C | | | | |

^[2] For SOT363-2 (TSSOP6) package: P_{tot} derates linearly with 3.7 mW/K above 83 °C. For SOT457 (SC-74; TSOP6) package: P_{tot} derates linearly with 4.1 mW/K above 89 °C.

11. Static characteristics

Table 7. Static characteristics for 74HC2G14

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|----------------------|---------------------------|---|------|------|------|------|
| T _{amb} = 2 | 25 °C | | | | | |
| V _{OH} | HIGH-level output voltage | $V_I = V_{T+}$ or V_{T-} | | | | |
| | | I _O = -20 μA; V _{CC} = 2.0 V | 1.9 | 2.0 | - | V |
| | | I _O = -20 μA; V _{CC} = 4.5 V | 4.4 | 4.5 | - | V |
| | | I _O = -20 μA; V _{CC} = 6.0 V | 5.9 | 6.0 | - | V |
| | | I _O = -4.0 mA; V _{CC} = 4.5 V | 4.18 | 4.32 | - | V |
| | | I _O = -5.2 mA; V _{CC} = 6.0 V | 5.68 | 5.81 | - | V |
| V _{OL} L | LOW-level output voltage | $V_I = V_{T+}$ or V_{T-} | | | | |
| | | I _O = 20 μA; V _{CC} = 2.0 V | - | 0 | 0.1 | V |
| | | I _O = 20 μA; V _{CC} = 4.5 V | - | 0 | 0.1 | V |
| | | I _O = 20 μA; V _{CC} = 6.0 V | - | 0 | 0.1 | V |
| | | I _O = 4.0 mA; V _{CC} = 4.5 V | - | 0.15 | 0.26 | V |
| | | I _O = 5.2 mA; V _{CC} = 6.0 V | - | 0.16 | 0.26 | V |
| l _l | input leakage current | $V_I = GND \text{ or } V_{CC}; V_{CC} = 6.0 \text{ V}$ | - | - | ±0.1 | μA |
| I _{CC} | supply current | V_I = GND or V_{CC} ; I_O = 0 μ A; V_{CC} = 6.0 V | - | - | 1.0 | μA |
| Cı | input capacitance | | - | 2.0 | - | pF |
| T _{amb} = - | 40 °C to +85 °C | | | | | |
| V _{OH} | HIGH-level output voltage | $V_I = V_{T+}$ or V_{T-} | | | | |
| | | I _O = -20 μA; V _{CC} = 2.0 V | 1.9 | - | - | V |
| | | I _O = -20 μA; V _{CC} = 4.5 V | 4.4 | - | - | V |
| | | I _O = -20 μA; V _{CC} = 6.0 V | 5.9 | - | - | V |
| | | I_{O} = -4.0 mA; V_{CC} = 4.5 V | 4.13 | - | - | V |
| | | I _O = -5.2 mA; V _{CC} = 6.0 V; | 5.63 | - | - | V |
| V _{OL} | LOW-level output voltage | $V_I = V_{T+}$ or V_{T-} | | | | |
| | | I _O = 20 μA; V _{CC} = 2.0 V | - | - | 0.1 | V |
| | | I _O = 20 μA; V _{CC} = 4.5 V | - | - | 0.1 | V |
| | | I _O = 20 μA; V _{CC} = 6.0 V | - | - | 0.1 | V |
| | | I _O = 4.0 mA; V _{CC} = 4.5 V | - | - | 0.33 | V |
| | | I _O = 5.2 mA; V _{CC} = 6.0 V | - | - | 0.33 | V |
| lį | input leakage current | $V_I = GND \text{ or } V_{CC}; V_{CC} = 6.0 \text{ V}$ | - | - | ±1.0 | μΑ |
| I _{CC} | supply current | V_I = GND or V_{CC} ; I_O = 0 μ A; V_{CC} = 6.0 V | - | - | 10.0 | μΑ |

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|----------------------|---------------------------|---|-----|-----|------|------|
| T _{amb} = - | 40 °C to +125 °C | | ' | | | |
| V _{OH} | HIGH-level output voltage | $V_I = V_{T+}$ or V_{T-} | | | | |
| | | I _O = -20 μA; V _{CC} = 2.0 V | 1.9 | - | - | V |
| | | I _O = -20 μA; V _{CC} = 4.5 V | 4.4 | - | - | V |
| | | I _O = -20 μA; V _{CC} = 6.0 V | 5.9 | - | - | V |
| | | I _O = -4.0 mA; V _{CC} = 4.5 V | 3.7 | - | - | V |
| | | I _O = -5.2 mA; V _{CC} = 6.0 V; | 5.2 | - | - | V |
| V _{OL} | LOW-level output voltage | $V_I = V_{T+}$ or V_{T-} | | | | |
| | | I _O = 20 μA; V _{CC} = 2.0 V | - | - | 0.1 | V |
| | | I _O = 20 μA; V _{CC} = 4.5 V | - | - | 0.1 | V |
| | | I _O = 20 μA; V _{CC} = 6.0 V | - | - | 0.1 | V |
| | | I _O = 4.0 mA; V _{CC} = 4.5 V | - | - | 0.4 | V |
| | | I _O = 5.2 mA; V _{CC} = 6.0 V | - | - | 0.4 | V |
| I _I | input leakage current | $V_I = GND \text{ or } V_{CC}; V_{CC} = 6.0 \text{ V}$ | - | - | ±1.0 | μA |
| I _{CC} | supply current | V_I = GND or V_{CC} ; I_O = 0 μ A; V_{CC} = 6.0 V | - | - | 20.0 | μΑ |

Table 8. Static characteristics for 74HCT2G14

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|----------------------|---------------------------|--|------|------|------|------|
| T _{amb} = 2 | 5 °C | | - | 1 | | |
| V _{OH} | HIGH-level output voltage | $V_I = V_{T+}$ or V_{T-} | | | | |
| | | I _O = -20 μA; V _{CC} = 4.5 V | 4.4 | 4.5 | - | V |
| | | I _O = -4.0 mA; V _{CC} = 4.5 V | 4.18 | 4.32 | - | V |
| V _{OL} | LOW-level output voltage | $V_I = V_{T+}$ or V_{T-} | | | | |
| | | I _O = 20 μA; V _{CC} = 4.5 V | - | 0 | 0.1 | V |
| | | I _O = 4.0 mA; V _{CC} = 4.5 V | - | 0.15 | 0.26 | V |
| l _l | input leakage current | $V_I = GND \text{ or } V_{CC}; V_{CC} = 5.5 \text{ V}$ | - | - | ±0.1 | μΑ |
| I _{CC} | supply current | V_{I} = GND or V_{CC} ; I_{O} = 0 μ A; V_{CC} = 5.5 V | - | - | 1.0 | μΑ |
| ΔI _{CC} | additional supply current | $V_I = V_{CC} - 2.1 \text{ V}; V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}; I_O = 0 \mu\text{A}$ | - | - | 300 | μΑ |
| Cı | input capacitance | | - | 2.0 | - | pF |
| T _{amb} = - | 40 °C to +85 °C | | 1 | 1 | | |
| V _{OH} | HIGH-level output voltage | $V_I = V_{T+}$ or V_{T-} | | | | |
| | | I _O = -20 μA; V _{CC} = 4.5 V | 4.4 | - | - | V |
| | | I _O = -4.0 mA; V _{CC} = 4.5 V | 4.13 | - | - | V |
| V _{OL} | LOW-level output voltage | $V_I = V_{T+}$ or V_{T-} | | | | |
| | | I _O = 20 μA; V _{CC} = 4.5 V | - | - | 0.1 | V |
| | | I _O = 4.0 mA; V _{CC} = 4.5 V | - | - | 0.33 | V |
| I _I | input leakage current | $V_I = GND \text{ or } V_{CC}; V_{CC} = 5.5 \text{ V}$ | - | - | ±1.0 | μA |
| I _{CC} | supply current | $V_I = GND \text{ or } V_{CC}; I_O = 0 \mu\text{A}; V_{CC} = 5.5 \text{ V}$ | - | - | 10.0 | μA |
| Δl _{CC} | additional supply current | $V_1 = V_{CC} - 2.1 \text{ V}; V_{CC} = 4.5 \text{ V} \text{ to } 5.5 \text{ V}; I_O = 0 \mu\text{A}$ | - | - | 375 | μΑ |

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| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|----------------------|---------------------------|--|-----|-----|------|------|
| T _{amb} = - | 40 °C to +125 °C | | | | | · |
| V _{OH} | HIGH-level output voltage | $V_I = V_{T+}$ or V_{T-} | | | | |
| | | I _O = -20 μA; V _{CC} = 4.5 V | 4.4 | - | - | V |
| | | I _O = -4.0 mA; V _{CC} = 4.5 V | 3.7 | - | - | V |
| V _{OL} | LOW-level output voltage | $V_I = V_{T+}$ or V_{T-} | | | | |
| | | I _O = 20 μA; V _{CC} = 4.5 V | - | - | 0.1 | V |
| | | I _O = 4.0 mA; V _{CC} = 4.5 V | - | - | 0.4 | V |
| I _I | input leakage current | $V_I = GND \text{ or } V_{CC}; V_{CC} = 5.5 \text{ V}$ | - | - | ±1.0 | μA |
| Icc | supply current | V_{I} = GND or V_{CC} ; I_{O} = 0 μ A; V_{CC} = 5.5 V | - | - | 20.0 | μΑ |
| ΔI_{CC} | additional supply current | $V_I = V_{CC}$ - 2.1 V; V_{CC} = 4.5 V to 5.5 V; I_O = 0 μ A | - | - | 410 | μA |

12. Dynamic characteristics

Table 9. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); for test circuit see Fig. 6.

| Symbol | Parameter | Conditions | | | 25 °C | | -40 °C t | o +85 °C | -40 °C to | +125 °C | Unit |
|-----------------|-------------------------------------|---|-----|-----|-------|-----|----------|----------|-----------|---------|------|
| | | | | Min | Тур | Max | Min | Max | Min | Max | |
| 74HC2G | 14 | | | | | | | | | | |
| t _{pd} | propagation | nA to nY; see Fig. 5 | [1] | | | | | | | | |
| | delay | $V_{CC} = 2.0 \text{ V}; C_L = 50 \text{ pF}$ | | - | 53 | 125 | - | 155 | - | 190 | ns |
| | | $V_{CC} = 4.5 \text{ V}; C_L = 50 \text{ pF}$ | | - | 16 | 25 | - | 31 | - | 38 | ns |
| | | V _{CC} = 6.0 V; C _L = 50 pF | | - | 13 | 21 | - | 26 | - | 32 | ns |
| t _t | transition time | nY; see Fig. 5 | [2] | | | | | | | | |
| | | V _{CC} = 2.0 V; C _L = 50 pF | | - | 20 | 75 | - | 95 | - | 110 | ns |
| | | V _{CC} = 4.5 V; C _L = 50 pF | | - | 7 | 15 | - | 19 | - | 22 | ns |
| | | $V_{CC} = 6.0 \text{ V}; C_L = 50 \text{ pF}$ | | - | 5 | 13 | - | 16 | - | 19 | ns |
| C _{PD} | power dissipation capacitance | V _I = GND to V _{CC} | [3] | - | 10 | - | - | - | | - | pF |
| 74HCT2 | G14 | | | | | | ı | | ı | | |
| t _{pd} | propagation | nA to nY; see Fig. 5 | [1] | | | | | | | | |
| · | delay | V _{CC} = 4.5 V; C _L = 50 pF | | - | 21 | 32 | - | 40 | - | 48 | ns |
| t _t | transition time | nY; see Fig. 5 | [2] | | | | | | | | |
| | | V _{CC} = 4.5 V; C _L = 50 pF | | - | 6 | 15 | - | 19 | - | 22 | ns |
| C _{PD} | power dissipation capacitance | $V_I = GND$ to $V_{CC} - 1.5 V$ | [3] | - | 10 | - | - | - | - | - | pF |

- [1] t_{pd} is the same as t_{PLH} and t_{PHL}
- [2] t_t is the same as t_{TLH} and t_{THL}
 [3] C_{PD} is used to determine the dynamic power dissipation (P_D in μW).

 $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma (C_L \times V_{CC}^2 \times f_o)$ where:

 f_i = input frequency in MHz;

f_o = output frequency in MHz;

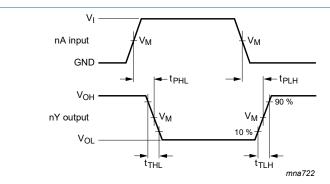
C_L = output load capacitance in pF;

V_{CC} = supply voltage in V;

N = number of inputs switching;

 $\Sigma(C_L \times V_{CC}^2 \times f_0)$ = sum of the outputs.

12.1. Waveforms and test circuit



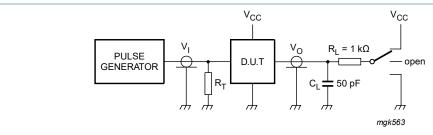
Measurement points are given in Table 10.

 $\ensuremath{V_{\text{OL}}}$ and $\ensuremath{V_{\text{OH}}}$ are typical voltage output levels that occur with the output load.

Fig. 5. The data input (nA) to output (nY) propagation delays and output transition times

Table 10. Measurement points

| Туре | Input | Output | | | | | | |
|-----------|--------------------|------------------------|-------------|--------------------|--|--|--|--|
| | V_{M} | V_{l} | $t_r = t_f$ | V_{M} | | | | |
| 74HC2G14 | 0.5V _{CC} | GND to V _{CC} | 6.0 ns | 0.5V _{CC} | | | | |
| 74HCT2G14 | 1.3 V | GND to 3.0 V | 6.0 ns | 1.3 V | | | | |



Test data is given in Table 11.

Definitions test circuit:

 R_L = Load resistance.

C_L = Load capacitance including jig and probe capacitance.

 R_T = Termination resistance should be equal to output impedance Z_o of the pulse generator.

Fig. 6. Test circuit for measuring switching times

Table 11. Test data

| Туре | Input | Test | |
|-----------|------------------------|---------------------------------|-------------------------------------|
| | VI | t _r , t _f | t _{PHL} , t _{PLH} |
| 74HC2G14 | GND to V _{CC} | 6 ns | open |
| 74HCT2G14 | GND to 3.0 V | 6 ns | open |

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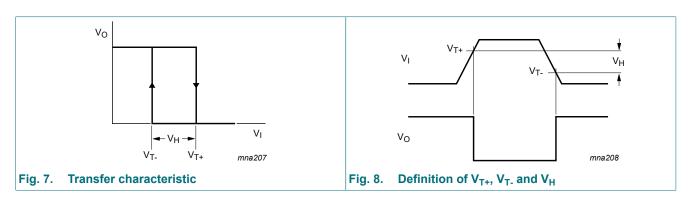
13. Transfer characteristics

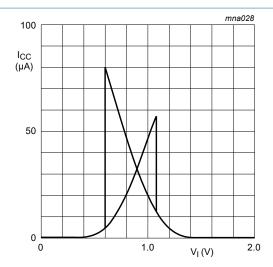
Table 12. Transfer characteristics

Voltages are referenced to GND (ground = 0 V); for test circuit see Fig. 6.

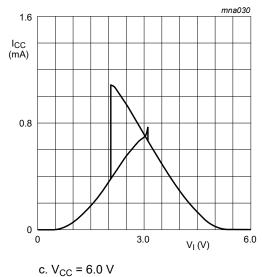
| Symbol | Parameter | Conditions | 25 °C | | -40 °C to +85 °C | | -40 °C to +125 °C | | Unit | |
|-----------------|-------------------------------------|---|-------|------|------------------|------|-------------------|------|------|---|
| | | | Min | Тур | Max | Min | Max | Min | Max | |
| 74HC2G | 14 | | | | 1 | 1 | | | | |
| V _{T+} | positive-going threshold voltage | see <u>Fig. 7</u> , <u>Fig. 8</u> | | | | | | | | |
| | | V _{CC} = 2.0 V | 1.00 | 1.18 | 1.50 | 1.00 | 1.50 | 1.00 | 1.50 | V |
| | | V _{CC} = 4.5 V | 2.30 | 2.60 | 3.15 | 2.30 | 3.15 | 2.30 | 3.15 | V |
| | | V _{CC} = 6.0 V | 3.00 | 3.46 | 4.20 | 3.00 | 4.20 | 3.00 | 4.20 | V |
| V _{T-} | negative-going | see <u>Fig. 7</u> , <u>Fig. 8</u> | | | | | | | | |
| | threshold voltage | V _{CC} = 2.0 V | 0.30 | 0.60 | 0.90 | 0.30 | 0.90 | 0.30 | 0.90 | V |
| | | V _{CC} = 4.5 V | 1.13 | 1.47 | 2.00 | 1.13 | 2.00 | 1.13 | 2.00 | V |
| | | V _{CC} = 6.0 V | 1.50 | 2.06 | 2.60 | 1.50 | 2.60 | 1.50 | 2.60 | V |
| V _H | hysteresis voltage | (V _{T+} - V _{T-}); see <u>Fig. 7</u> , <u>Fig. 8</u> and <u>Fig. 9</u> | | | | | | | | |
| | | V _{CC} = 2.0 V | 0.30 | 0.60 | 1.00 | 0.30 | 1.00 | 0.30 | 1.00 | V |
| | | V _{CC} = 4.5 V | 0.60 | 1.13 | 1.40 | 0.60 | 1.40 | 0.60 | 1.40 | V |
| | | V _{CC} = 6.0 V | 0.80 | 1.40 | 1.70 | 0.80 | 1.70 | 0.80 | 1.70 | V |
| 74HCT2 | G14 | | ' | | • | | | | | |
| V _{T+} | positive-going threshold voltage | see Fig. 7 and Fig. 8 | | | | | | | | |
| | | V _{CC} = 4.5 V | 1.20 | 1.58 | 1.90 | 1.20 | 1.90 | 1.20 | 1.90 | V |
| | | V _{CC} = 5.5 V | 1.40 | 1.78 | 2.10 | 1.40 | 2.10 | 1.40 | 2.10 | V |
| V _{T-} | negative-going threshold voltage | see Fig. 7 and Fig. 8 | | | | | | | | |
| | | V _{CC} = 4.5 V | 0.50 | 0.87 | 1.20 | 0.50 | 1.20 | 0.50 | 1.20 | V |
| | | V _{CC} = 5.5 V | 0.60 | 1.11 | 1.40 | 0.60 | 1.40 | 0.60 | 1.40 | V |
| V _H | hysteresis voltage | (V _{T+} - V _{T-}); see <u>Fig. 7</u> , <u>Fig. 8</u> and <u>Fig. 10</u> | | | | | | | | |
| | | V _{CC} = 4.5 V | 0.40 | 0.71 | - | 0.40 | - | 0.40 | - | V |
| | | V _{CC} = 5.5 V | 0.40 | 0.67 | - | 0.40 | - | 0.40 | - | V |

13.1. Waveforms transfer characteristics

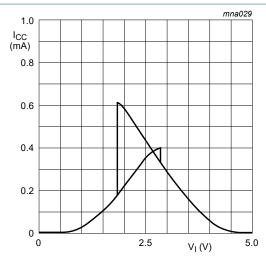














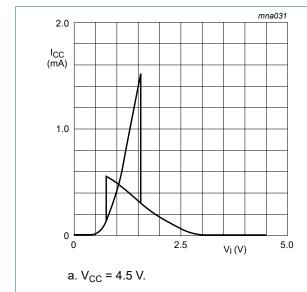
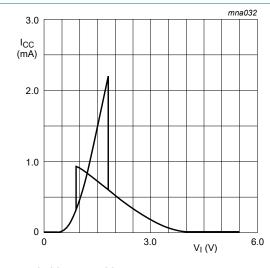


Fig. 10. Typical 74HCT2G14 transfer characteristics



b. $V_{CC} = 5.5 \text{ V}$.

14. Application information

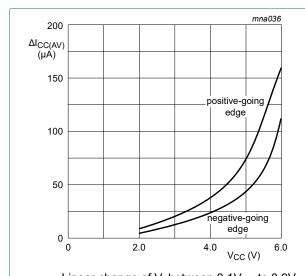
The slow input rise and fall times cause additional power dissipation, this can be calculated using the following formula:

 $P_{add} = f_i \times (t_r \times \Delta I_{CC(AV)} + t_f \times \Delta I_{CC(AV)}) \times V_{CC}$ where:

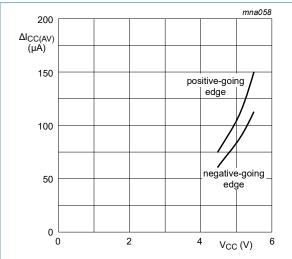
- P_{add} = additional power dissipation (μW);
- f_i = input frequency (MHz);
- t_r = input rise time (ns); 10 % to 90 %;
- t_f = input fall time (ns); 90 % to 10 %;
- $\Delta I_{CC(AV)}$ = average additional supply current (μA).

 $\Delta I_{CC(AV)}$ differs with positive or negative input transitions, as shown in Fig. 11 and Fig. 12.

An example of a relaxation circuit using the 74HC2G14; 74HCT2G14 is shown in Fig. 13.

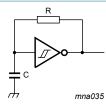


Linear change of V_I between $0.1V_{CC}$ to $0.9V_{CC}$



Linear change of V_I between $0.1V_{CC}$ to $0.9V_{CC}$

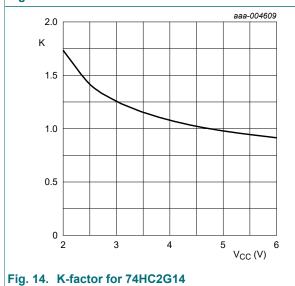
Fig. 12. $\Delta I_{CC(AV)}$ as a function of V_{CC} for 74HCT2G14



For 74HC2G14: $f = \frac{1}{T} \approx \frac{1}{0.8 \times RC}$ For 74HCT2G14: $f = \frac{1}{T} \approx \frac{1}{0.67 \times RC}$

For K-factor, see Fig. 14 or Fig. 15

Fig. 13. Relaxation oscillator



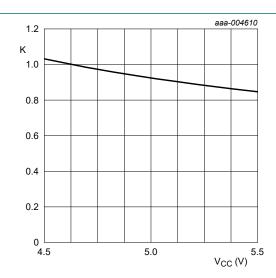


Fig. 15. K-factor for 74HCT2G14

15. Package outline

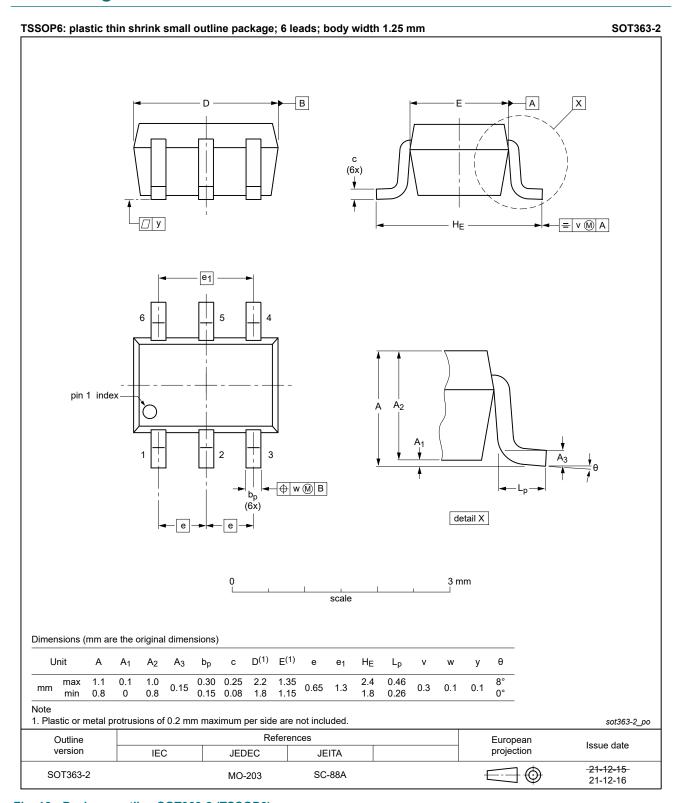


Fig. 16. Package outline SOT363-2 (TSSOP6)

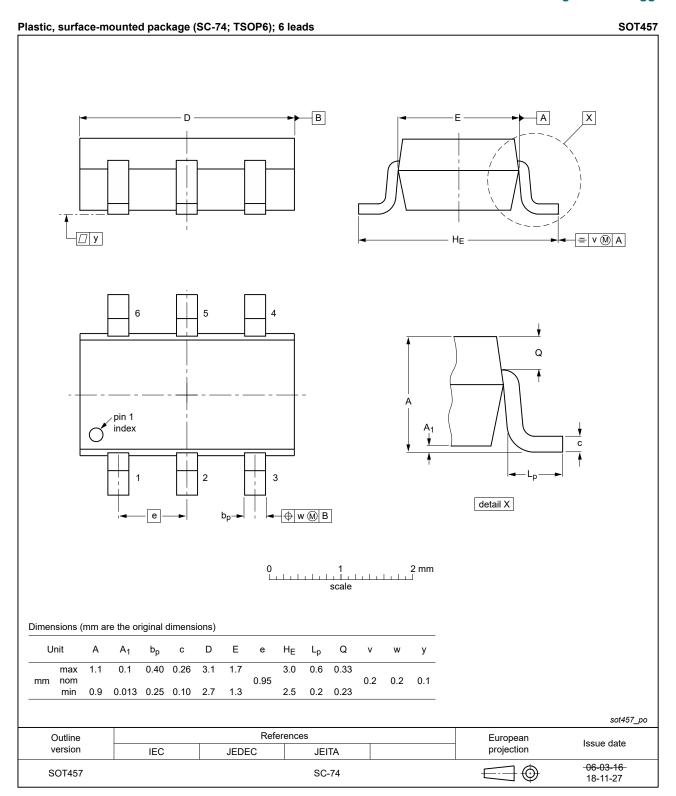


Fig. 17. Package outline SOT457 (SC-74; TSOP6)

16. Abbreviations

Table 13. Abbreviations

| Acronym | Description |
|---------|---|
| CMOS | Complementary Metal-Oxide Semiconductor |
| DUT | Device Under Test |
| ESD | ElectroStatic Discharge |
| НВМ | Human Body Model |
| MM | Machine Model |
| TTL | Transistor-Transistor Logic |

17. Revision history

Table 14. Revision history

| Document ID | Release date | Data sheet status | Change notice | Supersedes | | |
|------------------|---|--|---------------|--|--|--|
| 74HC_HCT2G14 v.3 | 20220128 | Product data sheet | - | 74HC_HCT2G14 v.2 | | |
| Modifications: | guidelines o | The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia. | | | | |
| | Package St | Legal texts have been adapted to the new company name where appropriate. Package SOT363 (SC-88) changed to SOT363-2 (TSSOP6). | | | | |
| | Section 2 updated. Section 9: Derating values for P_{tot} total power dissipation updated. | | | | | |
| | • <u>Fig. 17</u> : Pac | Fig. 17: Package outline drawing SOT457 (SC-74; TSOP6) updated. | | | | |
| 74HC_HCT2G14 v.2 | 20140314 | Product data sheet | - | 74HC_HCT2G14 v.1 | | |
| Modifications: | • <u>Fig. 14</u> and | Fig. 14 and Fig. 15 added (typical K-factor for relaxation oscillator). | | | | |
| 74HC_HCT2G14 v.1 | 20061011 | Product data sheet | - | - | | |
| | | The state of the s | 1 | T. Control of the Con | | |

18. Legal information

Data sheet status

| Document status [1][2] | Product status [3] | Definition |
|--------------------------------|-----------------------|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification | This document contains data from the preliminary specification. |
| Product [short] data sheet | Production | This document contains the product specification. |

- Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
- The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the internet at https://www.nexperia.com.

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